STinysemi®

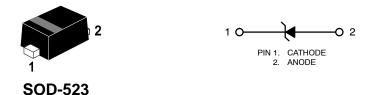
TESDL051AD52

Transient Voltage Suppressors for ESD Protection

FEATURES:

- Ultra Low Capacitance 0.5 pF
- Low Clamping Voltage
- Small Body Outline Dimensions: 0.047" x 0.032" (1.20 mm x 0.80 mm)
- Low Body Height: 0.016" (0.4 mm)
- Stand-off Voltage: 5 V
- Low Leakage
- Response Time is Typically < 1.0 ns
- IEC61000-4-2 Level 4 ESD Protection
- This is a Pb–Free Device

Circuit Diagram & Pin Configuration:



DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping	
TESDL051AD52	5L	3000/Tape&Reel	

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Contact Air		±10 ±15	kV
Total Power Dissipation on FR–5 Board (Note 1) @ T _A = 25°C	P _D	200	mW
Peak Pulse Power (tp= 8/20us)	P _{PP}	100	W
Storage Temperature Range	T _{stg}	-55 to +150	°C
Junction Temperature Range	Т _Ј	-55 to +125	°C
Lead Solder Temperature – Maximum (10 Second Duration)	ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

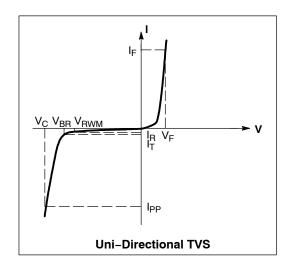
1. $FR-5 = 1.0 \times 0.75 \times 0.62$ in.

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ELECTRICAL CHARACTERISTICS QE^oC uploss otherwise noted) **/T**

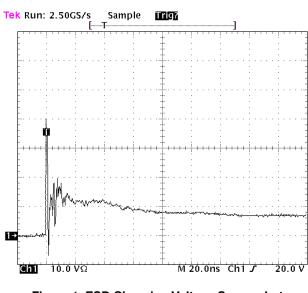
(I _A = 25°C unless otherwise noted)					
Symbol	Parameter				
I _{PP}	Maximum Reverse Peak Pulse Current				
V _C	Clamping Voltage @ I _{PP}				
V _{RWM}	Working Peak Reverse Voltage				
I _R	Maximum Reverse Leakage Current @ V _{RWM}				
V _{BR}	Breakdown Voltage @ I _T				
Ι _Τ	Test Current				
١ _F	Forward Current				
V _F	Forward Voltage @ I _F				
P _{pk}	Peak Power Dissipation				
С	Capacitance @ $V_R = 0$ and f = 1.0 MHz				

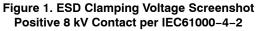


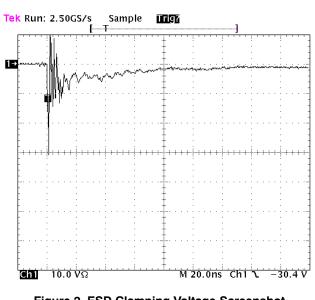
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted, V_F = 1.0 V Max. @ I_F = 10 mA for all types)

Device	V _{RWM} (V)	I _R (μΑ) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)	ŀŗ	C (pF)		V _C (V) @ Ipp = 1 A (Note 3)	v _c
Device	Max	Max	Min	mA	Тур	Max	Мах	Per IEC61000-4-2 (Note 4)
TESDL051AD52	5.0	1.0	5.4	1.0	0.5	0.9	9.8	Figures 1 and 2 See Below

V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C.
Surge current waveform per Figure 5.
For test procedure see Figures 3 and 4











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IEC 61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

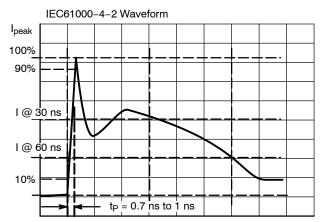


Figure 3. IEC61000-4-2 Spec

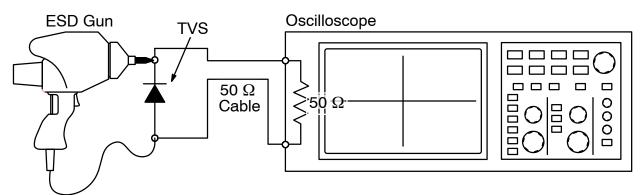
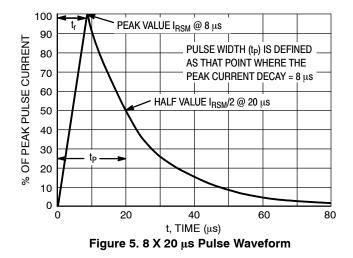


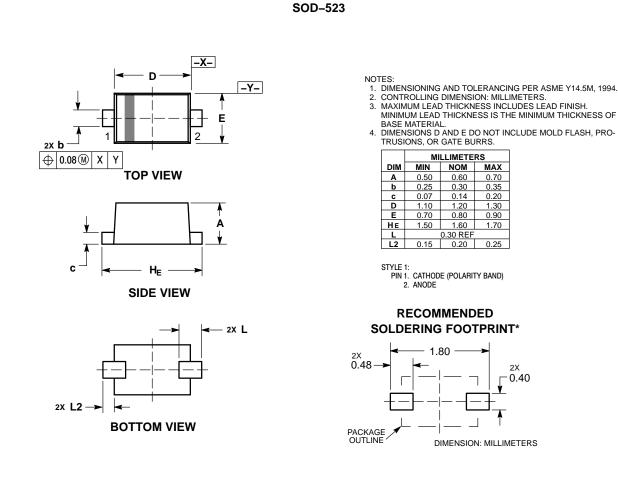
Figure 4. Diagram of ESD Test Setup





TESDL051AD52

PACKAGE DIMENSIONS



NOTICE

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The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Tintsemi elec Co., Ltd., or anyone on its behalf, assumes no responsibility or liability for any damagers resulting from such improper use of sale.

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